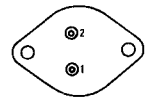
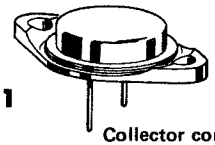
2N178 (GERMANIUM)
2N554
2N555



STYLE 1:
PIN 1. BASE
2. EMITTER
CASE-COLLECTOR



CASE 11

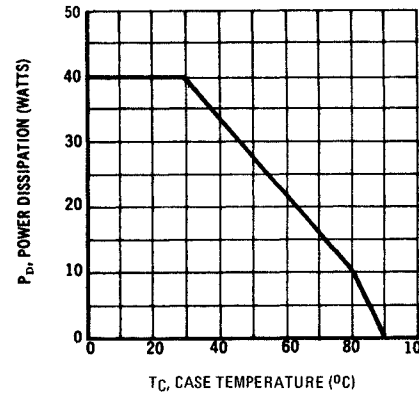
PNP germanium power transistor for non-critical power amplifier and power switching applications requiring economical components.

Collector connected to case

MAXIMUM RATINGS

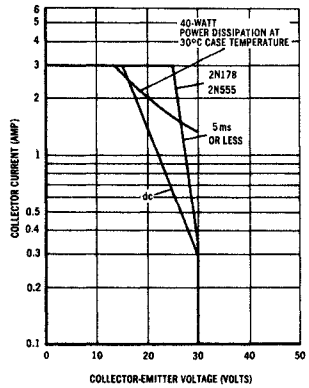
Rating	Symbol	2N178	2N554	2N555	Unit
Collector-Emitter Voltage	V_{CER}	30	16	30	Vdc
Collector-Base Voltage	V_{CB}	30	15	30	Vdc
Emitter-Base Voltage	V_{EB}	20	15	15	Vdc
Collector Current	I_C	3.0			Adc
Total Device Dissipation @ T_C = 80°C	P_D	10			Watts
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-40 to +90			°C

POWER-TEMPERATURE DERATING CURVE

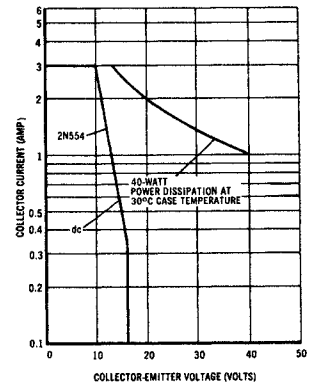


SAFE OPERATING AREAS

2N178, 2N555



2N554



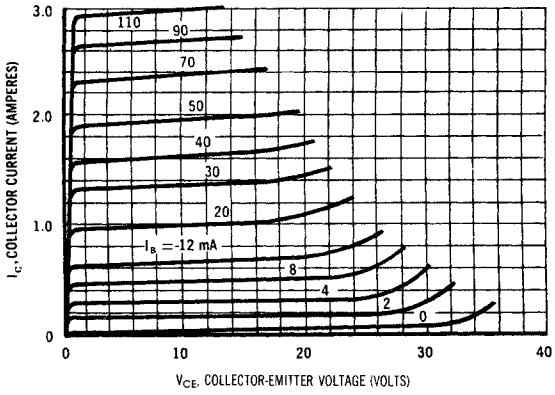
The Safe Operating Area Curves indicate I_C — V_{CE} limits below which the device will not go into secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a collector-emitter short. (Duty cycle of the excursions make no significant change in these safe areas.) To insure operation below the maximum T_J, the power-temperature derating curve must be observed for both steady state and pulse power conditions.

2N178, 2N554, 2N555 (continued)

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Collector-Emitter Breakdown Voltage (I_C = 330 mAdc, R_{BE} = 10Ω)	2N178	BV_{CER}	30	-	-	Vdc
	2N554		16	-	-	
	2N555		30	-	-	
Collector-Base Cutoff Current		I_{CBO}				mA
(V_{CB} = 2.0 Vdc, I_E = 0)	2N178		-	0.05	-	
(V_{VB} = 30 Vdc, I_E = 0)	2N178		-	-	3.0	
(V_{CB} = 15 Vdc, I_E = 0)	2N554		-	-	10.0	
(V_{CB} = 30 Vdc, I_E = 0)	2N555		-	-	20.0	
(V_{CB} = 30 Vdc, I_E = 0, T_C = 90°C)	2N178		-	-	20.0	
Emitter-Base Cutoff Current (V_{BE} = 10 Vdc, I_C = 0)	2N178	I_{EBO}	-	-	2.0	mA
ON CHARACTERISTICS						
DC Current Gain (I_C = 0.5 Adc, V_{CE} = 2.0 Vdc)	2N178	h_{FE}	15	-	45	-
	2N554		-	50	-	
	2N555		-	50		
Collector-Emitter Saturation Voltage (I_C = 3.0 Adc, I_B = 300 mAdc)		$V_{CE(sat)}$	-	0.6	-	Vdc
SMALL-SIGNAL CHARACTERISTICS						
Common-Emitter Cutoff Frequency (I_C = 0.5 Adc, V_{CE} = 12 Vdc, f = 1.0 kHz ref)	2N178	$f_{\alpha e}$	5.0	-	-	kHz
	2N554		-	6.0	-	
	2N555		-	6.0	-	
Small-Signal Current Gain (I_C = 0.5 Adc, V_{CE} = 2.0 Vdc, f = 1.0 kHz ref)	2N178	h_{fe}	-	30	-	-
	2N554		-	55	-	
	2N555		-	55	-	
Input Impedance (I_C = 0.5 Adc, V_{CE} = 2.0 Vdc, f = 1.0 kHz)	2N178	h_{ie}	8.0	25	-	Ohms
	2N554		-	25	-	
	2N555		-	25	-	
FUNCTIONAL TESTS						
Power Gain (V_{CE} = 12 Vdc, I_C = 0.5 Adc, P_{out} = 2.0 Watts, f = 1.0 kHz, R_S = 10 Ohms, R_L = 26.6 Ohms)	2N178	G_{PE}	28	-	33	dB
	2N554		20	35	-	
	2N555		25	35	-	
Total Harmonic Distortion (Under same conditions as power gain)	2N178		-	-	5.0	%

COLLECTOR CHARACTERISTICS



INPUT CURRENT versus INPUT DRIVE VOLTAGE

